Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIV)

2SK3564

Switching Regulator Applications

Low drain-source ON-resistance: $R_{DS (ON)} = 3.7 \Omega (typ.)$

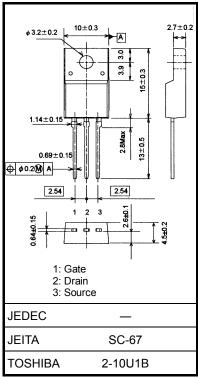
• High forward transfer admittance: |Y_{fs}| = 2.6 S (typ.)

Low leakage current: I_{DSS} = 100 μA (max) (V_{DS} = 720 V)

• Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	900	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	900	V	
Gate-source voltage		V _{GSS}	±30	V	
Drain current	DC (Note 1)	ID	3	А	
	Pulse (Note 1)	I _{DP}	9	A	
Drain power dissipati	on (Tc = 25°C)	PD	40	W	
Single pulse avalanche energy (Note 2)		E _{AS}	408	mJ	
Avalanche current		I _{AR}	3	Α	
Repetitive avalanche	energy (Note 3)	E _{AR}	4.0	mJ	
Channel temperature	,	T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

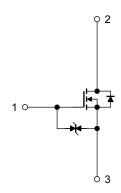
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	3.125	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$, L = 83 mH, $I_{AR} = 3.0 \text{ A}$, $R_G = 25 \Omega$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.



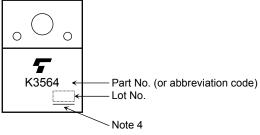
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cui	rent	I _{GSS}	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ
Gate-source breakdown voltage		V (BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V
Drain cut-off curr	ent	I _{DSS}	V _{DS} = 720 V, V _{GS} = 0 V	_	_	100	μА
Drain-source bre	akdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	900		_	٧
Gate threshold ve	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0		4.0	٧
Drain-source ON	-resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 1.5 A		3.7	4.3	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 20 V, I _D = 1.5 A	0.65	2.6	_	S
Input capacitance		C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	700	_	pF
Reverse transfer capacitance		C _{rss}		_	15	_	
Output capacitance		C _{oss}		_	75	_	
Switching time	Rise time	t _r	V_{GS} V_{OD}	_	20	_	
	Turn-on time	t _{on}		_	60	_	no
	Fall time	t _f		_	35	_	ns
	Turn-off time	t _{off}	Duty ≤ 1%, t _W = 10 μs	_	125	_	
Total gate charge		Qg		_	17	_	
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 3 \text{ A}$	_	10	_	nC
Gate-drain charge		Q _{gd}		_	7	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	_	_	_	3	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	9	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 3 A, V _{GS} = 0 V	_	_	-1.9	V
Reverse recovery time	t _{rr}	$I_{DR} = 3 \text{ A}, V_{GS} = 0 \text{ V},$	_	850	_	ns
Reverse recovery charge	Qrr	dI _{DR} /dt = 100 A/μs		4.7	_	μС

Marking

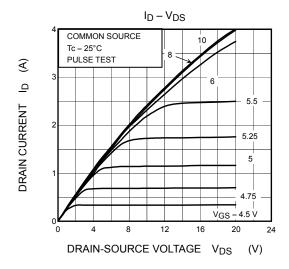


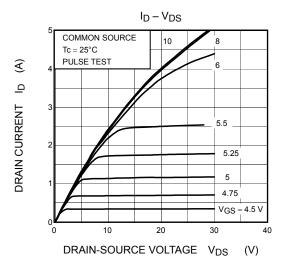
Note 4: A line under a Lot No. identifies the indication of product Labels.

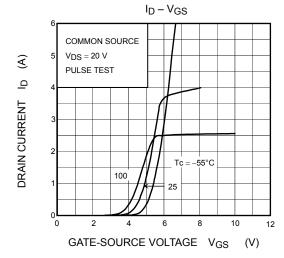
Not underlined: [[Pb]]/INCLUDES > MCV

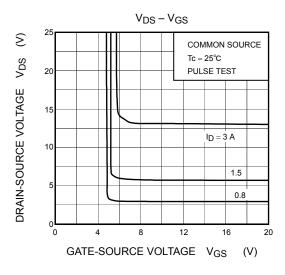
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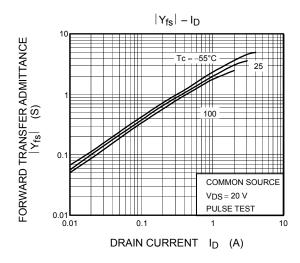
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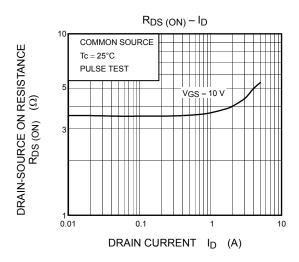




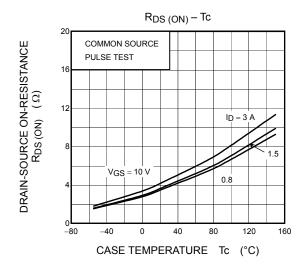


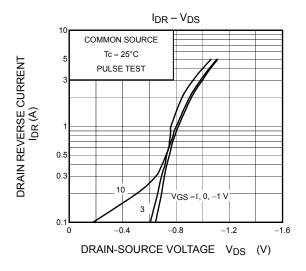


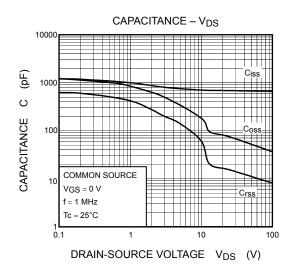


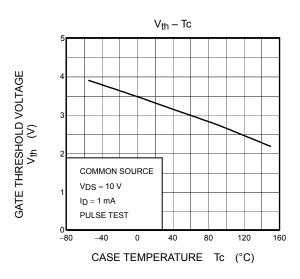


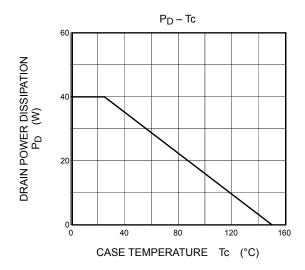
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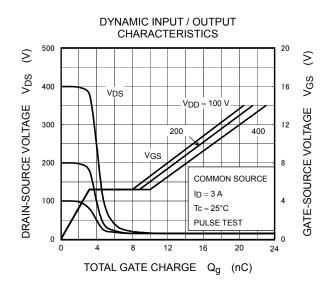


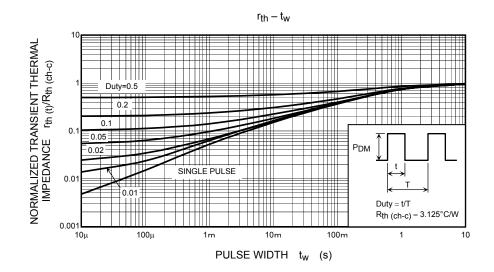


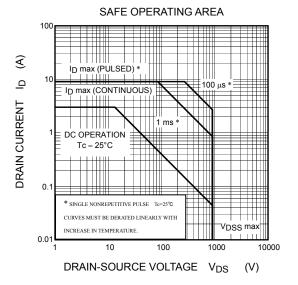


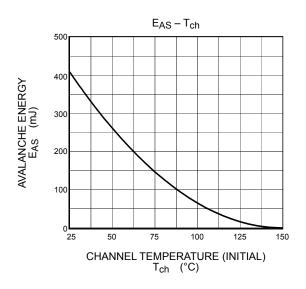


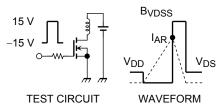












$$R_G = 25 \Omega$$

$$V_{DD} = 90 \text{ V, L} = 83 \text{ mH}$$

$$E_{AS} = \frac{1}{2} \cdot \text{L} \cdot \text{I}^2 \cdot \left(\frac{\text{BVDSS}}{\text{BVDSS} - \text{VDD}}\right)$$

5 2013-11-01

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